NSN 5961-01-310-9404

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# Function For Which Designed:

Amplifier

Internal Configuration:

Field effect

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

20.0 gate to source voltage and 80.0 drain to source voltage and 80.0 drain to gate voltage and 80.0 breakdown voltage, drain-to-source,

with all other terminals short-circuited to source and 2.0 gate to source threshold voltage and 6.0 gate to source threshold voltage

# **Current Rating Per Characteristic:**

2.00 amperes drain current and 1.80 amperes on-state drain current

## **Power Rating Per Characteristic:**

40.0 watts total device dissipation

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Shelf Life:

N/a

- Unit Of Measure:
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## Demilitarization:

Yes - demil/mli

Fiig:

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